

S9702

RGB color sensor

The S9702 is a color sensor molded into a plastic package having a 3-channel (RGB) photodiode sensitive to the blue ($\lambda_p=460$ nm), green ($\lambda_p=540$ nm) and red ($\lambda_p=620$ nm) regions of the spectrum. The S9702 has a 3-segment (RGB) photosensitive area of $\square 1$ mm. When compared to the previous model (S9032-02), the S9702 is significantly miniaturized (package size 55% less in cubic volume, PC board mount space 43% less in area).

Features

- 3-channel (RGB) Si photodiode
- Surface-mount small plastic package
- Spectral response range close to the human eye sensitivity
- No sensitivity in the near IR region
- Photosensitive area: 3-segment (RGB) photosensitive area of $\square 1$ mm

Applications

- Portable or mobile equipment
- RGB-LCD backlight monitors
- Detectors for various light sources
- Color detection

Absolute maximum ratings

Parameter	Symbol	Value	Unit
Reverse voltage	V_R max	10	V
Operating temperature	T_{opr}	-25 to +85	°C
Storage temperature	T_{stg}	-40 to +85	°C

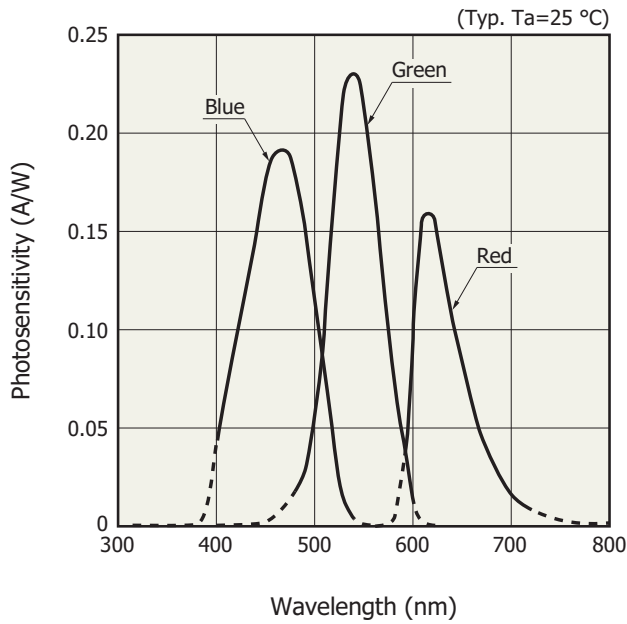
Note: Exceeding the absolute maximum ratings even momentarily may cause a drop in product quality. Always be sure to use the product within the absolute maximum ratings.

Electrical and optical characteristics ($T_a = 25$ °C, per element)

Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit	
Spectral response range	λ	Blue	-	400 to 540	-	nm	
		Green	-	480 to 600	-		
		Red	-	590 to 720	-		
Peak sensitivity wavelength	λ_p	Blue	-	460	-	nm	
		Green	-	540	-		
		Red	-	620	-		
Photosensitivity	S	$\lambda = \lambda_p$	Blue	0.13	0.18	-	A/W
			Green	0.18	0.23	-	
			Red	0.11	0.16	-	
Dark current	I_D	$V_R = 1$ V All elements	-	1	50	pA	
Temperature coefficient of I_D	T_{CID}		-	1.12	-	times/°C	
Rise time	t_r	$V_R = 0$ V, $R_L = 1$ k Ω 10 to 90%	-	0.1	1.0	μ s	
Terminal capacitance	C_t	$V_R = 0$ V, $f = 10$ kHz	-	12	25	pF	

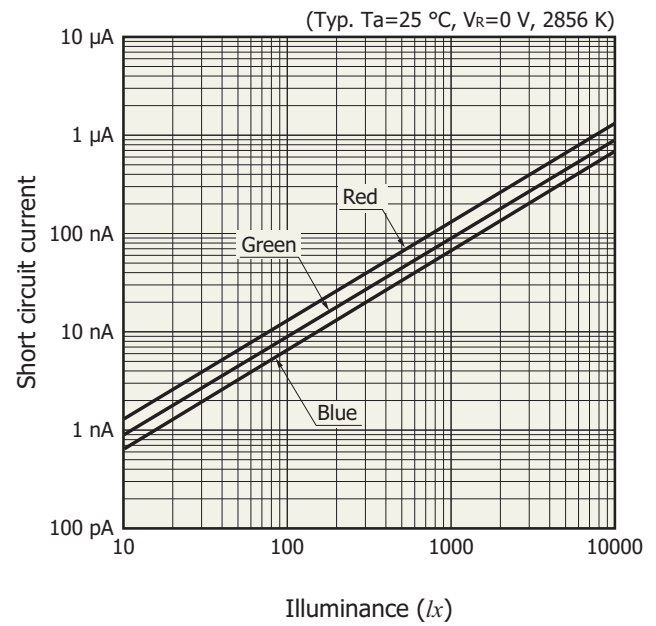
This product does not support lead-free soldering. For details on reflow soldering conditions, please contact our sales office.

Spectral response



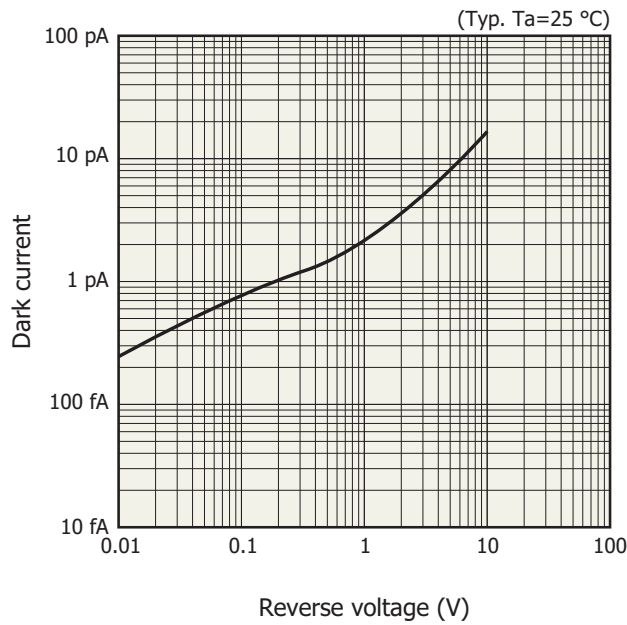
KSPDB0246EA

Linearity



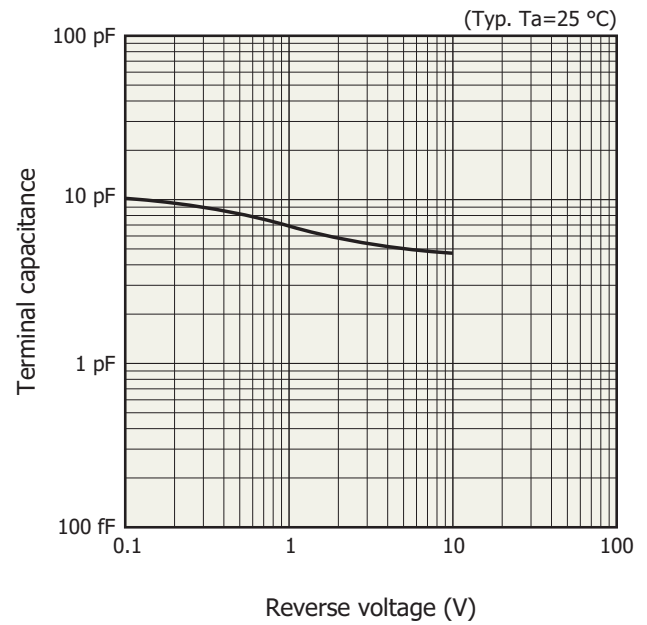
KSPDB0327EA

Dark current vs. reverse voltage



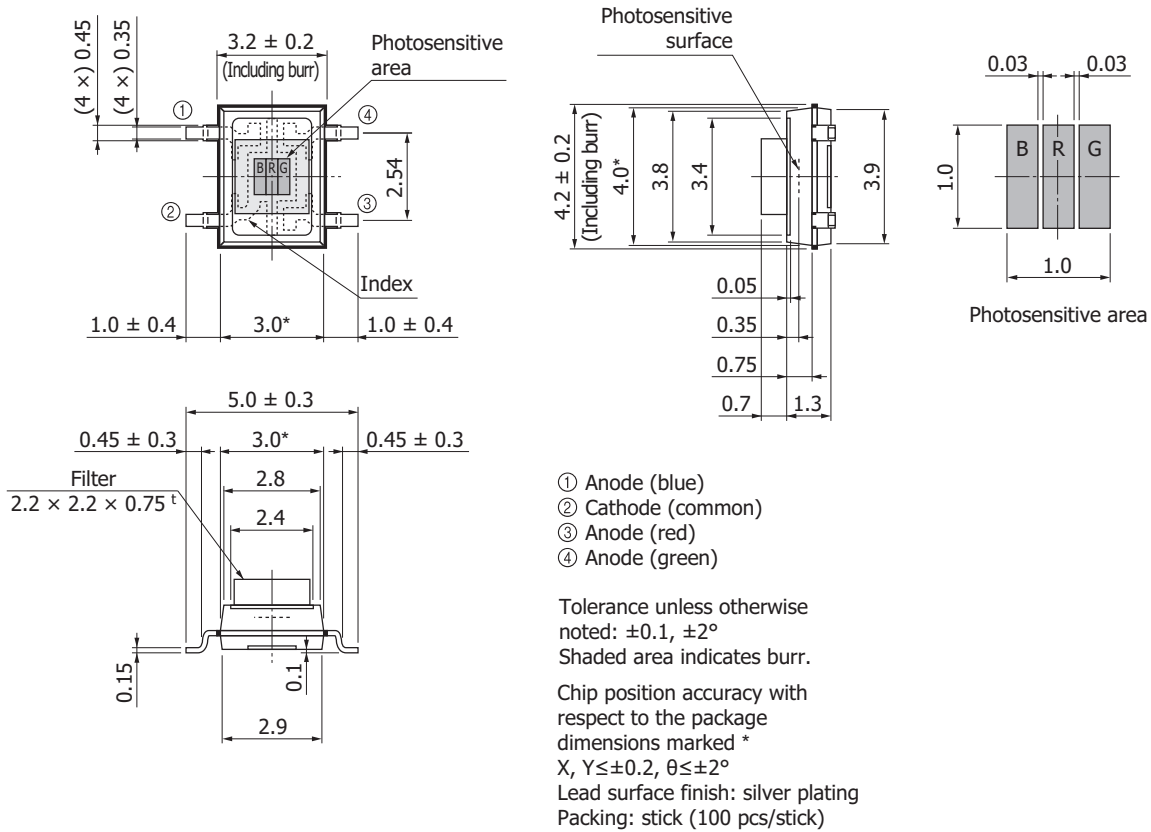
KSPDB0252EA

Terminal capacitance vs. reverse voltage



KSPDB0253EA












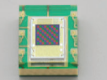

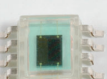


Dimensional outline (unit: mm)



KSPDA0170EC

Note: If excessive vibration is continuously applied to the glass filter, there is a risk that the filter may come off, so secure the glass filter with a holder.

Line-up of RGB color sensors

Type no.	Type	Photosensitive area size (mm)	Package (mm)	Peak sensitivity wavelength (nm)	Photosensitivity				Photo		
					B	G	R	IR			
S9032-02	Photodiode	 $\phi 2.0$	4 × 4.8 × 1.8 ^t 6-pin (filter 0.75 ^t)	B 460	B	0.18 (A/W) [$\lambda=460$ nm]					
				G 540	G	0.23 (A/W) [$\lambda=540$ nm]					
				R 620	R	0.16 (A/W) [$\lambda=620$ nm]					
S9702	Photodiode	 1.0 × 1.0	3 × 4 × 1.3 ^t 4-pin (filter 0.75 ^t)	B 460	B	0.18 (A/W) [$\lambda=460$ nm]					
				G 540	G	0.23 (A/W) [$\lambda=540$ nm]					
				R 620	R	0.16 (A/W) [$\lambda=620$ nm]					
S10917-35GT	Photodiode	 1.0 × 1.0	3 × 1.6 × 1.0 ^t COB (on-chip filter)	B 460	B	0.2 (A/W) [$\lambda=460$ nm]					
				G 540	G	0.23 (A/W) [$\lambda=540$ nm]					
				R 620	R	0.17 (A/W) [$\lambda=620$ nm]					
S10942-01CT	Photodiode	 1.0 × 1.0	3 × 1.6 × 1.0 ^t COB (on-chip filter)	*	B	0.21 (A/W) [$\lambda=460$ nm]					
					G	0.25 (A/W) [$\lambda=540$ nm]					
					R	0.45 (A/W) [$\lambda=640$ nm]					
S9706	Digital photo IC	 1.2 × 1.2	4 × 4.8 × 1.8 ^t 6-pin (filter 0.75 ^t)	B 465	Low	B	0.21 (LSB/lx)	High	B	1.9 (LSB/lx)	
				G 540		G	0.45 (LSB/lx)		G	4.1 (LSB/lx)	
				R 615		R	0.64 (LSB/lx)		R	5.8 (LSB/lx)	
S11012-01CR	Digital photo IC	 1.2 × 1.2	3.43 × 3.8 × 1.6 ^t COB (on-chip filter)	*	Low	B	0.3 (LSB/lx)	High	B	2.6 (LSB/lx)	
						G	0.6 (LSB/lx)		G	5.3 (LSB/lx)	
						R	1.4 (LSB/lx)		R	12.9 (LSB/lx)	
S11059-02DT /-03DS	I ² C compatible color sensor	 0.56 × 1.22	3 × 4.2 × 1.3 ^t 10-pin (on-chip filter)	B 460	Low	B	4.4 (count/lx)	High	B	44.8 (count/lx)	
				G 530		G	8.3 (count/lx)		G	85.0 (count/lx)	
				R 615		R	11.2 (count/lx)		R	117.0 (count/lx)	
				IR 855		IR	3.0 (count/lx)		IR	30.0 (count/lx)	
S11059-01WT	I ² C interface-compatible color sensor	 1.22 × 0.56	1.68 × 1.18 × 0.58 ^t WL-CSP (on-chip filter)	B 460	Low	B	3.35 (count/lx)	High	B	31.7 (count/lx)	
				G 530		G	7.61 (count/lx)		G	76.2 (count/lx)	
				R 615		R	9.48 (count/lx)		R	94.5 (count/lx)	
				IR 855		IR	1.66 (count/lx)		IR	15.3 (count/lx)	

* Refer to "Spectral response" of each datasheet.

Related information

www.hamamatsu.com/sp/ssd/doc_en.html

Precautions

- Notice
- Metal, ceramic, Plastic Package products/Precautions
- Surface mount type products/Precautions

Information described in this material is current as of July, 2014.

Product specifications are subject to change without prior notice due to improvements or other reasons. This document has been carefully prepared and the information contained is believed to be accurate. In rare cases, however, there may be inaccuracies such as text errors. Before using these products, always contact us for the delivery specification sheet to check the latest specifications.

The product warranty is valid for one year after delivery and is limited to product repair or replacement for defects discovered and reported to us within that one year period. However, even if within the warranty period we accept absolutely no liability for any loss caused by natural disasters or improper product use.

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